

#### WS726052

# High Precision, Low Noise Operational Amplifiers

## **Descriptions**

The WS726052 a dual high output drive CMOS operational amplifiers featured a peak output current of 350mA, and rail-to-rail output capability from a single 2.5V to 5.5V supply. This amplifier exhibits a high slew rate of 6V/ $\mu$ s and a gain-bandwidth product (GBP) of 11.5MHz. The WS726052 can drive typical headset levels (32 $\Omega$ ), as well as bias an RF power amplifier in wireless handset applications.

The WS726052 is available with MSL 3 Level in MSOP-8L package and MSL 2 Level in DFN2x2-8 package. Standard products are Pb-Free and halogen-Free.

## **Applications**

- RF Power Amplifier Biasing Controls
- Portable/Battery-Powered Audio Applications
- Portable Headphone Speaker Drivers (32Ω)
- Audio Hands-Free Car Phones (Kits)
- Laptop/Notebook Computers/TFT Panels
- Set-Top Boxes
- Digital-to-Analog Converter Buffers
- Transformer/Line Drivers

#### **Features**

- 350mA Output Drive Capability
- Low Input Offset Voltage: 5µV (MAX)
- Low Noise: 40nV/ Hz at 1kHz
- 300mA Current Limitation
- Over-Temperature Protection
- Supply Voltage Range: 2.5V to 5.5V
- Supply Current: 0.95mA/Amplifier (TYP)
- Gain-Bandwidth Product: 11.5MHz
- High Slew Rate: 6V/µs
- Voltage Gain (R<sub>L</sub> = 2kΩ): 140dB
- Power Supply Rejection Ratio: 135dB
- No Phase Reversal for Over-Driven Inputs
- Unity-Gain Stable for Capacitive Loads to 780pF

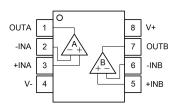
#### Http://www.omnivision-group.com

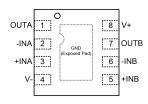




MSOP-8L

DFN2x2-8

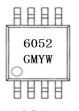


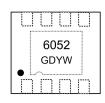


MSOP-8L

DFN2x2-8

Pin configuration (Top view)





MSOP-8L

DFN2x2-8

#### Marking

6052 = Device code

GM = Special code

GD = Special code

Y = Year code

W = Week code

#### **Order Information**

Device	Package	Shipping
WS726052M-8/TR	MSOP-8L	4000/Reel &Tape
WS726052D-8/TR	DFN2x2-8	3000/Reel &Tape



**Pin Descriptions** 

Pin Number	Symbol	Descriptions	
1	OUTA	Output of Channel A	
2	-INA	Inverting input of Channel A	
3	+INA	Non-inverting input of Channel A	
4	V-	Negative supply	
5	+INB	Non-inverting input of Channel B	
6	-INB	Inverting input of Channel B	
7	OUTB	Output of Channel B	
8	V+	Positive supply	

## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Supply Voltage, ([V+] - [V-])	Vs <sup>(2)</sup>	5.5	V
Operating Supply Voltage Range	$V_{IDR}$	2.5 to 5.5	V
All Other Pins	$V_{ICR}$	(V-)-0.3 to (V+)+0.3	V
Operating Fee-Air Temperature Range	T <sub>A</sub>	-40 to 125	Ĵ
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	Ĵ
Junction Temperature Range	$T_J$	150	Ω̂
Lead Temperature Range	TL	260	°C

#### Note:

- Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the
  device. These are only stress ratings, and functional operation of the device at these or any other
  conditions beyond those indicated under recommended operating conditions are not implied. Exposure
  to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. All voltage values, except differential voltage are with respect to network terminal.

## **ESD, Electrostatic Discharge Protection**

Symbol	Parameter	Condition	Minimum level	Unit	
HBM	Human Body Model ESD	MIL-STD-883H Method 3015.8	±8000	V	
TIBIVI	Traman Body Model 208	JEDEC-EIA/JESD22-A114A	_5555		
MM	Machine Model ESD	JEDEC-EIA/JESD22-A115	±400	V	
CDM	Charged Device Model ESD	JEDEC-EIA/JESD22-C101E	±2000	V	

#### Note:

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. Will Semiconductor Ltd. recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



#### **Electronics Characteristics**

The \*denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}C$ ,  $V_S = 5V$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $R_{load} = 2k\Omega$ ,  $C_{load} = 20pF$ .

Symbol	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS		
	INPUT CHARACTERISTICS							
Vos	Input Offset Voltage			1	5	μV		
V <sub>CM</sub>	Input Common Mode Voltage Range		(V-) - 0.1		(V+) + 0.1	V		
CMRR	Common Mode Rejection Ratio	$(V-) - 0.1V < V_{CM} < (V+) + 0.1V$	120	135		dB		
A <sub>OL</sub>	Open-Loop Voltage Gain	$(V-) + 0.1V < V_{OUT} < (V+) - 0.1V,$ $R_{load} = 2k\Omega$	120	140		dB		
OUTPUT	CHARACTERISTICS		'	l				
Vон	Output Voltage Swing from Rail to V+	$R_{load} = 150\Omega$		72	85	mV		
V <sub>OL</sub>	Output Voltage Swing from Rail to V-	$R_{load} = 150\Omega$		112	125	mV		
I <sub>SC+</sub>	Output Short-Circuit Current to V+		315	342		mA		
I <sub>SC-</sub>	Output Short-Circuit Current to V-		275	295				
POWER	SUPPLY							
Vs	Specified Voltage Range		2.5		5.5	V		
IQ	Quiescent Current/Amplifier	I <sub>OUT</sub> = 0		827	1300	μA		
PSRR	Power Supply Rejection	V+ = 2.5V to 5.5V, V <sub>CM</sub> =V+/2V	120	135				
PORK	Ratio	V+ - 2.3V tO 3.3V, VCM - V+/2V				dB		
DYNAMI	C PERFORMANCE							
	Gain-Bandwidth Product	G = +100, C <sub>load</sub> = 20pF		11.5		MHz		
	Slew Rate	$G = +1, V_{OUT} = 2V_{P-P}$		6		V/µs		
NOISE								
	Input Voltage Noise	f = 0.1Hz to 10Hz		8.0		µV <sub>P-P</sub>		
	Innut Voltage Noise Density	f = 1kHz		40		nV/ √ Hz		
	Input Voltage Noise Density	f = 10kHz		8		110/ √ 112		

#### Note:

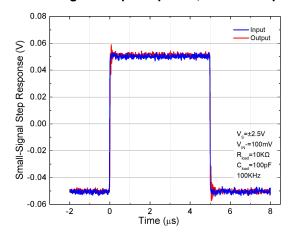
- Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.
- 2. A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.



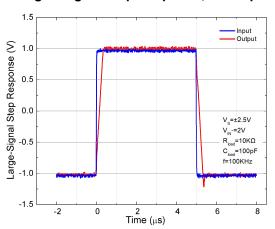
### **Typical Characteristics**

At  $T_A=25^{\circ}C$ ,  $V_S=\pm2.5V$ ,  $V_{CM}=0V$ ,  $R_{load}=2k\Omega$ ,  $C_{load}=20pF$ , unless otherwise noted.

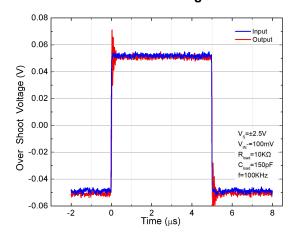
#### Small - signal Step Response, 100mV Step



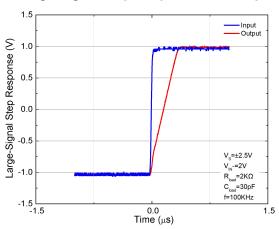
#### Large - Signal Step Response, 2V Step



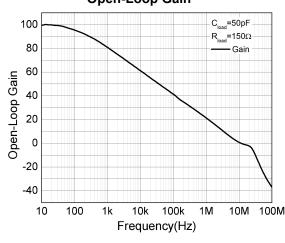
#### **Over Shoot Voltage**



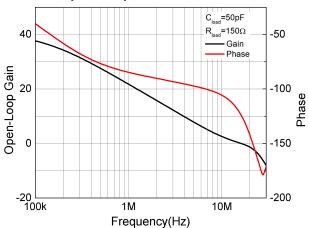
Large-Signal Step Response2, 2V Step



## **Open-Loop Gain**



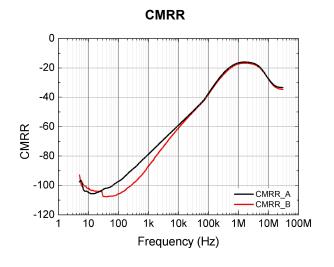
**Open-Loop Gain and Phase** 

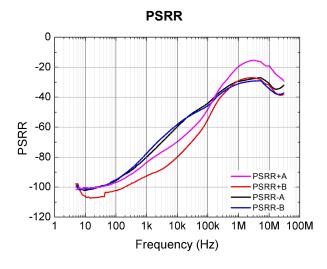




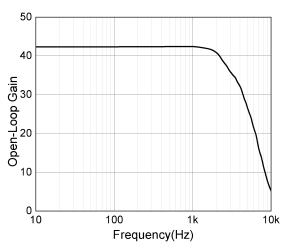
## **Typical Characteristics (continued)**

 $T_A$ =25°C,  $V_S$ =±2.5V,  $V_{CM}$ =0V,  $R_{load}$  = 2k $\Omega$ ,  $C_{load}$  = 20pF, unless otherwise noted.

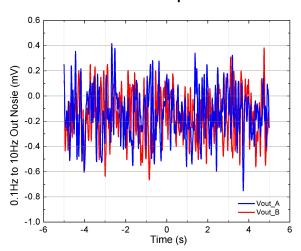




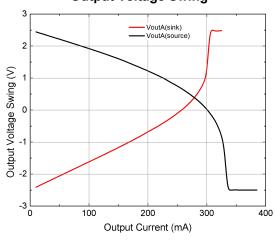




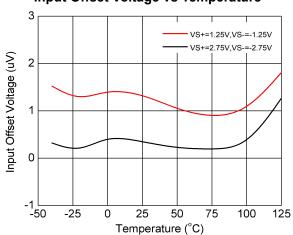
#### 0.1Hz to 10Hz Output-Nosie



## **Output Voltage Swing**



## Input Offset Voltage vs Temperature

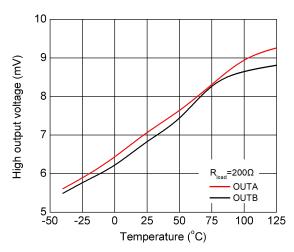




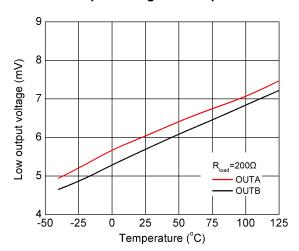
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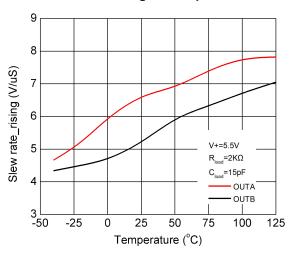
## **High Output Voltage vs Temperature**



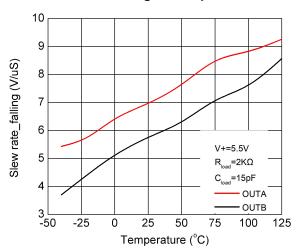
#### **Low Output Voltage vs Temperature**



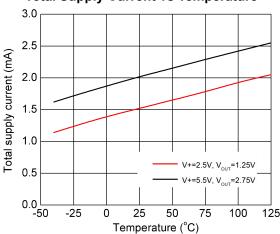
#### Slew Rate rising vs Temperature



#### Slew Rate falling vs Temperature



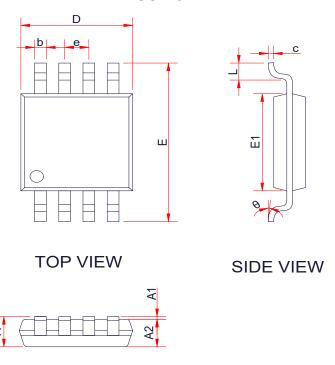
#### **Total Supply Current vs Temperature**





# PACKAGE OUTLINE DIMENSIONS





SIDE VIEW

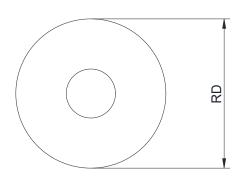
Symbol	Dimensions In Millimeters (mm)				
	Min.	Тур.	Max.		
А	-	-	1.10		
A1	0.02	-	0.15		
A2	0.75	0.80	0.95		
b	0.25	0.25 -			
С	0.09	-	0.23		
D	2.90	3.00	3.10		
E	4.75	4.75 4.90			
E1	2.90	2.90 3.00			
е	0.65 BSC				
L	0.40	-	0.80		
θ	0°	- 6°			



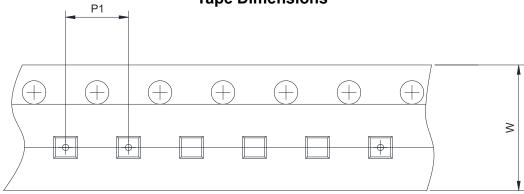
## **TAPE AND REEL INFORMATION**

## MSOP-8L

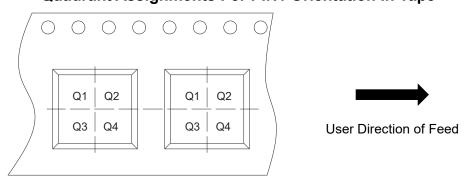
## **Reel Dimensions**



# **Tape Dimensions**



# **Quadrant Assignments For PIN1 Orientation In Tape**

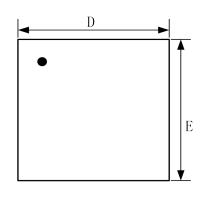


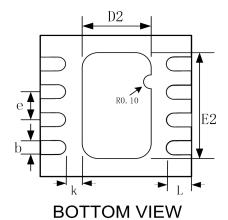
RD	Reel Dimension	7inch	▼ 13inch		
W	Overall width of the carrier tape	☐ 8mm	<b>▼</b> 12mm		
P1	Pitch between successive cavity centers	2mm	4mm	<b>☑</b> 8mm	
Pin1	Pin1 Quadrant	<b>☑</b> Q1	□ Q2	□ Q3	□ Q4



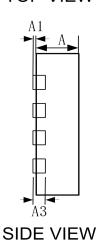
## **PACKAGE OUTLINE DIMENSIONS**

## **DFN2×2-8**





**TOP VIEW** 



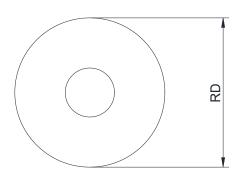
**Symbol Dimensions In Millimeters (mm)** Min. Max. Тур. 0.70 0.75 0.80 Α Α1 0.00 0.02 0.05 А3 0.20 REF b 0.19 0.24 0.29 D 2.00 BSC Ε 2.00 BSC D2 0.80 0.75 0.85 E2 1.25 1.30 1.35 0.50 BSC L 0.30 0.35 0.40 k 0.20



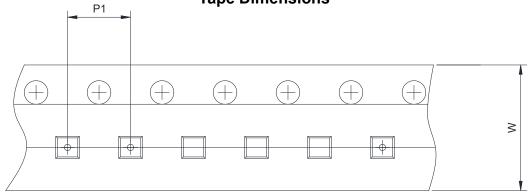
## **TAPE AND REEL INFORMATION**

## **DFN2×2-8**

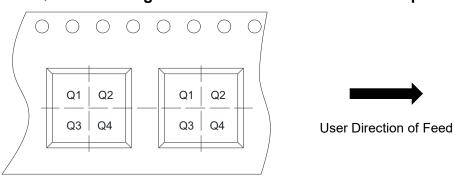
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